NSN 5961-01-009-6324

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-009-6324
Inclosure Material:
Plastic
Overall Length:
0.615 inches
Overall Height:
0.190 inches
Overall Width:
0.420 inches
Mounting Facility Quantity:
1
Mounting Method:
Unthreaded hole
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
200.0 breakover voltage, dc
Current Rating Per Characteristic:
80.00 amperes forward current, average absolute
Maximum Operating Tempurature Per Measurement Point:
100.0 degrees celsius junction
Terminal Type And Quantity:
3 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0